

SANYO	No.2391	2SK771
		N-Channel Junction Silicon FET Low-Frequency General-Purpose Amp Applications

Applications

- Variable resistors, analog switches, AF amp, constant-current circuit

Features

- Adoption of FBET process
- Very small-sized package permitting sets to be made smaller and slimmer

Absolute Maximum Ratings at Ta=25°C

			unit
Drain to Source Voltage	V_{DSX}	40	V
Gate to Drain Voltage	V_{GDS}	-40	V
Gate Current	I_G	10	mA
Drain Current	I_D	20	mA
Allowable Power Dissipation	P_D	200	mW
Junction Temperature	T_J	150	°C
Storage Temperature	T_{stg}	-55 to +150	°C

Electrical Characteristics at Ta=25°C

			min	typ	max	unit
Gate to Drain Breakdown Voltage	$V_{(BR)GDS}$	$I_G = -10\mu A, V_{DS} = 0$	-40			V
Gate Cutoff Current	I_{GSS}	$V_{GS} = -20V, V_{DS} = 0$			-1.0	nA
Cutoff Voltage	$I_{GS(off)}$	$V_{DS} = 10V, I_D = 1\mu A$	-0.3	-0.9	-2.5	V
Drain Current	I_{DSS}	$V_{DS} = 10V, V_{GS} = 0$	1.2*		12.0*	mA
Forward Transfer Admittance	$ Y_{fs} $	$V_{DS} = 10V, V_{GS} = 0, f = 1kHz$	4.5	9.0		mS
Input Capacitance	c_{iss}	$V_{DS} = 10V, V_{GS} = 0, f = 1MHz$		9.0		pF
Reverse Transfer Capacitance	c_{rss}	$V_{DS} = 10V, V_{GS} = 0, f = 1MHz$		2.1		pF
Noise Figure	NF	$V_{DS} = 10V, R_g = 1k\Omega, I_D = 1mA, f = 1kHz$		1.5		dB

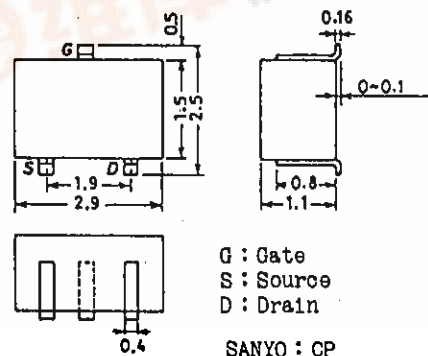
*: The 2SK771 is classified by I_{DSS} as follows (unit: mA):

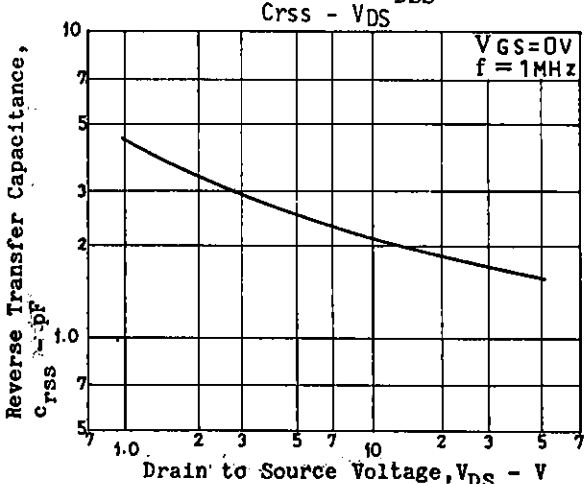
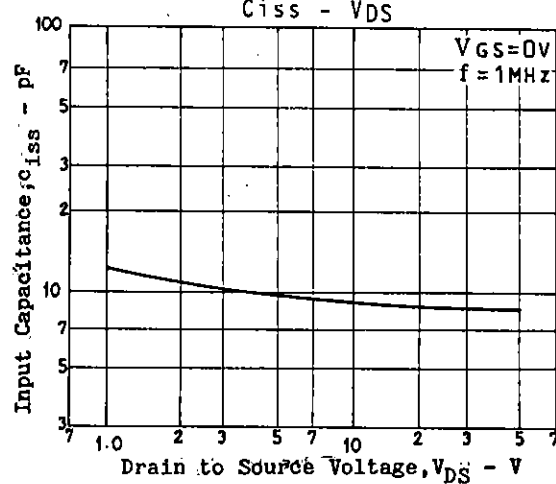
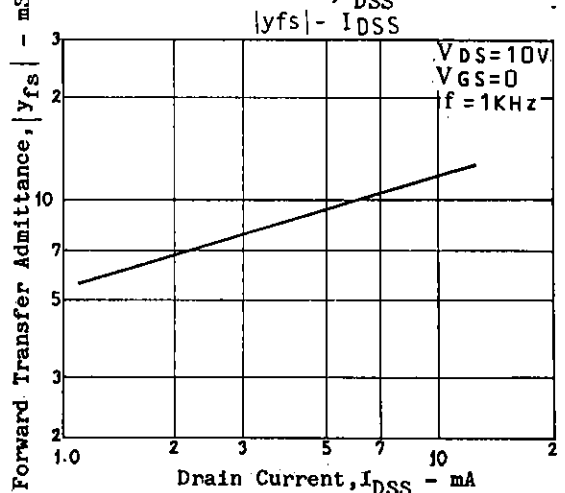
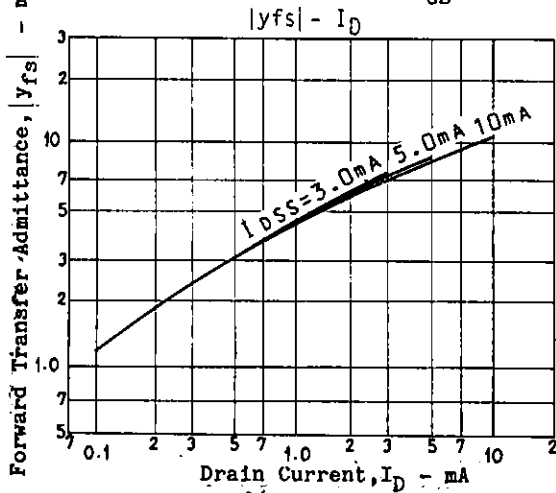
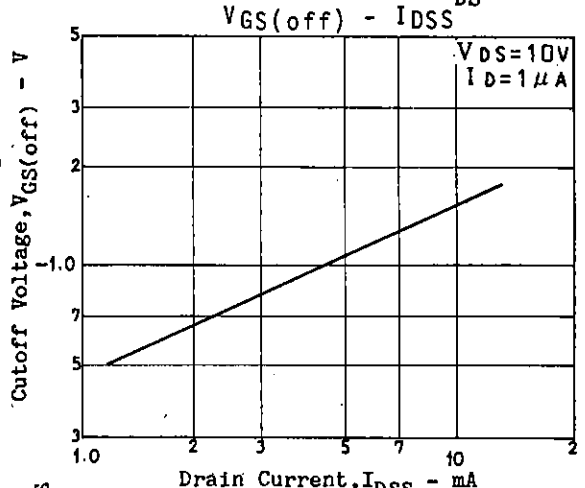
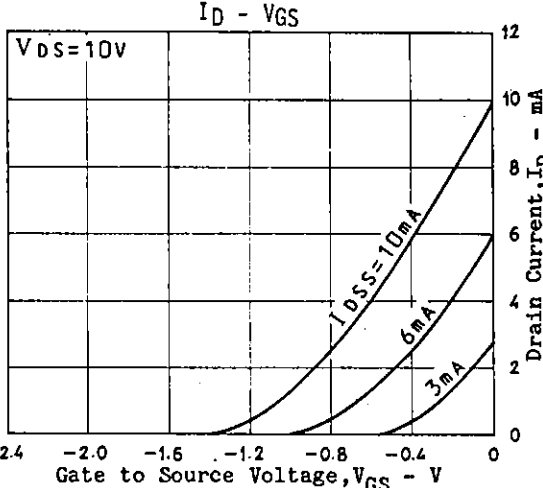
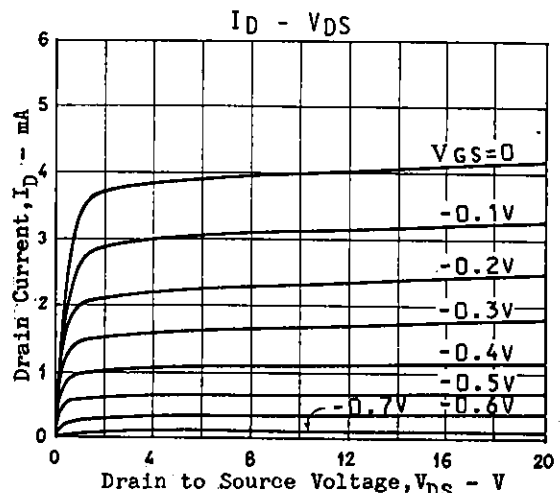
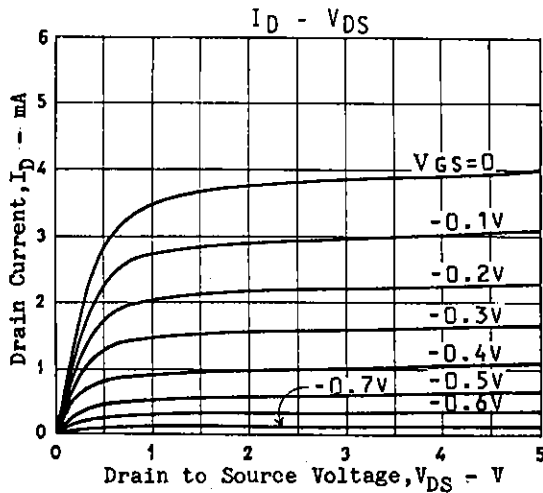
1.2	3	3.0	2.5	4	6.0	5.0	5	12.0
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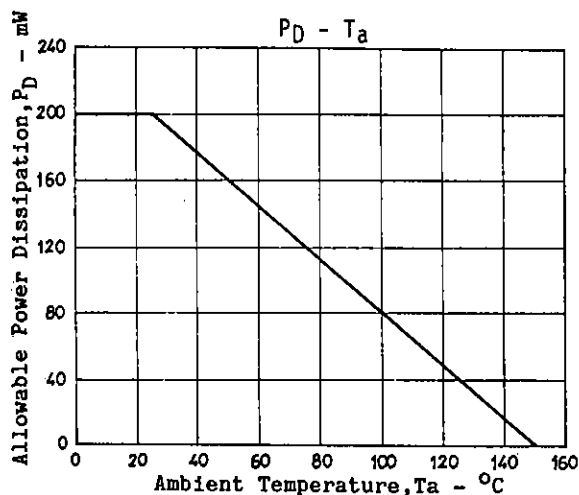
Marking : FJ

h_{FE} rank: 3, 4, 5

Package Dimensions 2050 (unit:mm)







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